A novel amorphous selenium based photosensor for liquid noble detectors

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In collaboration with:













DUNE

Strength of noble liquid TPCs: anti-correlated emission (and detection) of ionisation charge and scintillation VUV light

Despite being successful, the traditional wire technology of LArTPC for charge readout is too expensive to be implemented in the DUNE modules of Phase-II

The solution calls for a pixel-based charge readout

- Robust, simple construction & lower electronic noise

Problem: pixel boards are opaque and the photosensors should be inconveniently located

- over the cathode (huge voltages ~300 kV)
- behind the TPC walls (limited visibility)



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Our Proposal

A pixel sensitive to both scintillation VUV light and ionisation charge simultaneously (**Q+L sensor**)



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Benefits of this strategy:

- 1. Enormous light sensitive area -> Enormous Photon Yield
 - improved energy resolution
 Light + charge can boost the energy resolution up to 40% at low energies. <u>PRD 101 012010 (2020)</u>
 - light-enhanced particle identification
- 2. Extremely light granularity -> New detection capabilities
 - possible light imaging



Sensor Concept: making a photosensitive pixel

A photoconductive substrate over the pixel plane would allow for the integration of charge and light in only one sensor



Nygren & Mei arxiv: 1809.10213

Ideally the photoconductive material can be evaporated over the pixel plane

■ Potential materials: *amorphous selenium, nanoplatelets, organic semiconductors ….*

Simulation of the Q+L sensor in a TPC

Developing a dedicated simulation tool to study the scientific impact of the Q+L sensor on the DUNE experiment

Questions to answer:

Can we do light imaging, calorimetry and time discrimination with a Q+L sensor in a DUNE-VD geometry?

- Which physics channels can benefit from this technology? solar and supernova neutrinos, proton decay, ...
- Which are the minimum requirements for this sensor? quantum efficiency, sensitive area, granularity...



VD layout most likely for the DUNE PHASE-II modules

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How?

Full Geant4 simulations (or photon libraries) are prohibitively slow (heavy) for DUNE-like geometries and the enormous amount of photons

We need to develop fast optical methods that allow the simulation of scintillation light

- *Semi-Analytic Model* (EPJC 81 (2021) 4, 349) to predict the number of photons observed by the light sensors and the arrival times distributions (Isotropic emission + propagation effects)

- Anticorrelation of charge and light taken into account in the simulations



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fast simulation methods

Parameterization of the transport time distributions as a function of the distance

Propagation effects depend on the detector geometry

 $N_{\gamma} = N_{\Omega} \times GH'(d, \theta, d_T)/cos(\theta),$

Dedicated calibration for a DUNE-VD geometry

Amorphous Selenium (aSe)

Material commonly used in medicine for imaging diagnoses: X-Ray radiography at room temperature

Properties:

- 1. High absorption coefficient for 128 nm photons -> Layer of 100 nm enough for 100% absorption
- 2. Favorable transport properties
 - -> 1 photon produce 1.3 electron-hole pairs
- 3. Intrinsic gain: avalanche multiplication for high fields
 - -> ~1000 electrons per photon for 80V/µm

Q-Pix design choice between 0.3 and 1.0 fC per reset time (1800 - 6000 electrons) $\eta = 1 - e^{-\alpha L}$ Q-Pix technology compatible!!



FIG. 6. The spectral dependence of the absorption coefficient, α , of amorphous selenium.

Working Principle of the Q+L sensor

1. Scintillation VUV light is absorbed in the aSe substrate

- -> Photons get to the sensor in ns
- -> Carriers start moving
- -> If E-field strong enough ($80V/\mu m$) avalanche multiplication

2. Charge is collected, after drifting, as in regular pixels

-> Charge signal gets to the pixels after drifting times of ~ms



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Main Challenge ??

Reach avalanche multiplication for cryogenic conditions

-> 80V/µm is a really high field

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Proof of Principle & First Prototype

MAIN GOAL:

Test a-Se coating in a PCB at cryogenic temperature and see light signal



JINST 18 P01029 (2023)

■ PCB implemented with a commercial interdigitated board with 127 µm trace spacing and 35 µm trace thickness.

- > 99.999% a-Se was deposited by thermal evaporation
- Selenium layer of 1.2 µm





Horizontal Geometry

Experimental SetUp

JINST 18 P01029 (2023)

Custom made vacuum chamber with temperature control by flashing nitrogen



Detail of the SetUp:

VUV light source: Xenon Flash Lamp

-> 5 Watt Hamamatsu L11316-11

- Custom HV/readout system
 - -> HV via a DC/DC converter (±750V)
 - -> 2 polarities
 - -> charge read via a decoupling capacitor
- Low noise charge sensitive amplifier
- Electric fields: 2.7 5.2 V/µm

The PCB is mounted on a copper block in contact with a heat exchanger Cooling control: 1 kelvin/minute between 290K - 77K

Results (I): Waveforms at different temperatures

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The peak amplitude clearly reduces at the lowest temperatures

Results (I): Some light at cryogenic temperatures



- Integral of the peaks is definitively non-zero
- Pulse shape consistent with a response due to a signal from the flash lamp
- At lowest temperatures, the peak amplitude is higher when collecting electrons

- Future LArTPCs will move to a pixelated solution for charge readout
- This will require new light systems against the traditional ones
- We propose a novel solution: light sensitive pixels (Q+L sensor)
- A reliable simulation tool is in place to evaluate the enhancement of this technology in the physics reach of DUNE
- A potential photosensitive material is the amorphous selenium
- The first prototype has shown the proof-of-principle of the device, robustness at cryogenic conditions and response to VUV light

Back Up

Nygren & Mei arXiv: 1809.10213



Better Energy Resolution

Combining light and charge information has been proven to boos energy resolution in a LArTPC, especially at low energies LArIAT, PRD 101 012010 (2020

Q+L improves energy resolution for electros < 40 MeV by:

- 10% for 10 pe/MeV light yield
- 20% for 20 pe/MeV light yield
- 40% for 100 pe/MeV light yield

compared to Q-only reconstruction



Schematic of the setup



Preservation of Argon Purity



Time evolution of the peak amplitude

